

CHONGQING CLOUDCHILD TECHNOLOGY CO., LTD

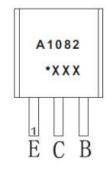
TO-92 Plastic-Encapsulate Transistors

2SA1082 TRANSISTOR (NPN)

FEATURES

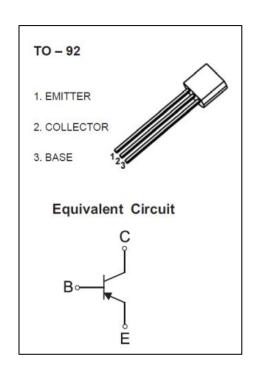
- Low Frequency Amplifier
- AEC Q101 Qualified

MARKING



A1082=Device code
Solid dot=Green molding compound device,
if none,the normal device

XXX=Code



ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
2SA1082	2SA1082 TO-92		1000pcs/Bag
2SA1082-TA TO-92		Таре	2000pcs/Box

MAXIMUM RATINGS (Ta=25C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	-120	V
V _{CEO}	Collector-Emitter Voltage	-120	V
V _{EBO}	Emitter-Base Voltage	-5	V
Ic	Collector Current	-0.1	Α
Pc	Collector Power Dissipation	480	mW
ROJA	Thermal Resistance From Junction To Ambient 312		°C/W
T _J ,T _{stg}	Operation Junction and Storage Temperature Range -55∼+175 °C		°C

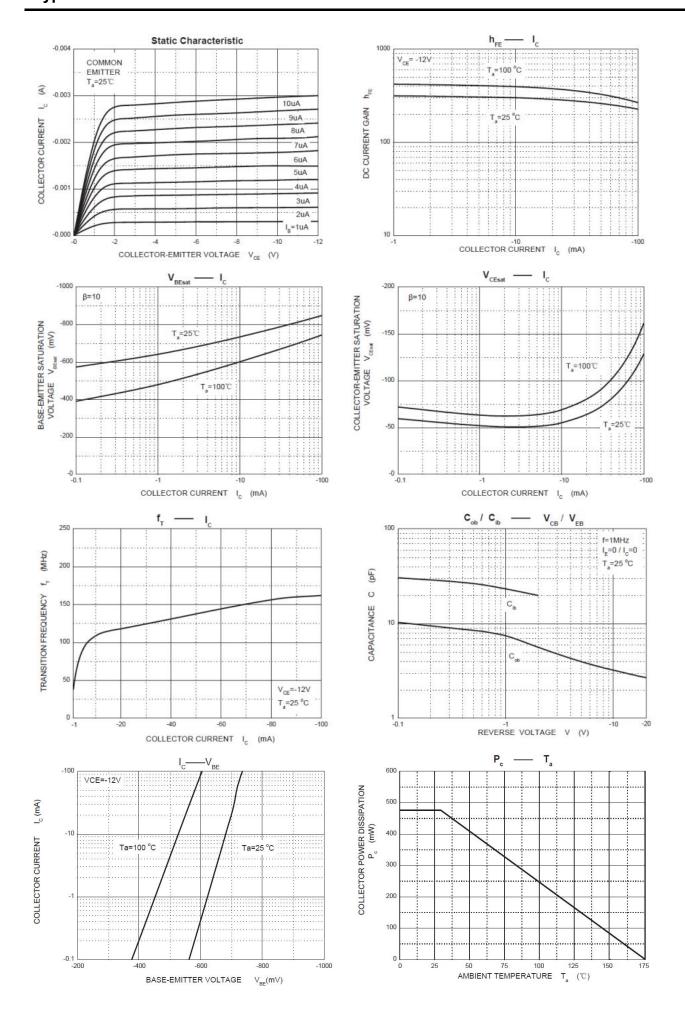
${\tt ELECTRICAL\ CHARACTERISTICS}(T_a \hbox{\tt =} 25\, \hbox{\tt C}\ unless\ otherwise\ specified})$

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =- 0.01mA,I _E =0	-120			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	R)CEO I _C =-1mA,I _B =0				V
Emitter-base breakdown voltage	V _{(BR)EBO}	_{3O} I _E =-0.01mA,I _C =0				V
Collector cut-off current	I _{CBO}	V _{CB} =-50V,I _E =0			-0.1	KA
Emitter cut-off current	I _{EBO}	V _{EB} =-2V,I _C =0			-0.1	KA
DC current gain	h _{FE}	V _{CE} =-12V, I _C =-2mA	250		800	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =-10mA,I _B =-1mA			-0.2	V
Base-emitter voltage	V _{BE}	V _{CE} =-12V, I _C =-2mA		-0.6		V
Collector output capacitance	C _{ob}	V _{CB} =-10V,I _E =0, f=1MHz		3.5		pF
Transition frequency	f⊤	Vce=-12V,Ic=-2mA		90		MHz

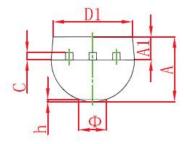
CLASSIFICATION OF h_{FE}

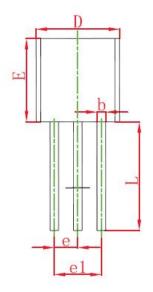
RANK	D	E	
RANGE	250-500	400-800	

Typical Characteristics



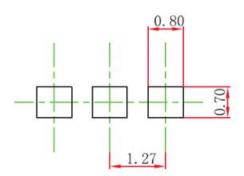
TO-29 Package Outline Dimensions





Complete	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	3.300	3.700	0.130	0.146	
A1	1.100	1.400	0.043	0.055	
b	0.380	0.550	0.015	0.022	
С	0.360	0.510	0.014	0.020	
D	4.300	4.700	0.169	0.185	
D1	3.430		0.135		
E	4.300	4.700	0.169	0.185	
е	1.270) TYP	0.050	TYP	
e1	2.440	2.640	0.096	0.104	
L	14.100	14.500	0.555	0.571	
٧		1.600		0.063	
h	0.000	0.380	0.000	0.015	

TO-29 Suggested Pad Layout



Note:

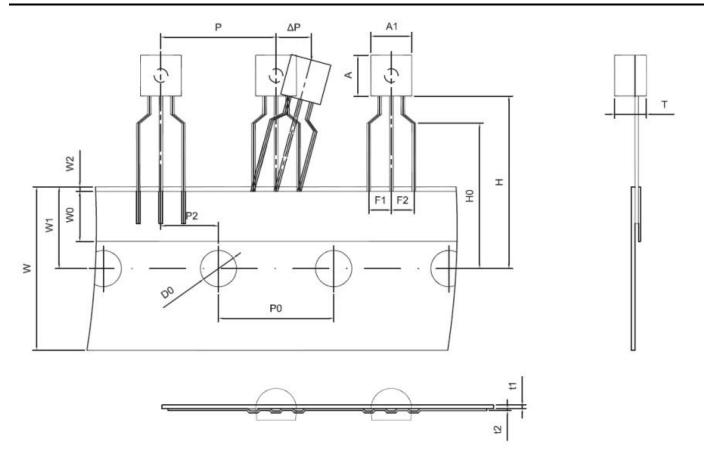
- Controlling dimension:in millimeters.
- General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.

NOTICE

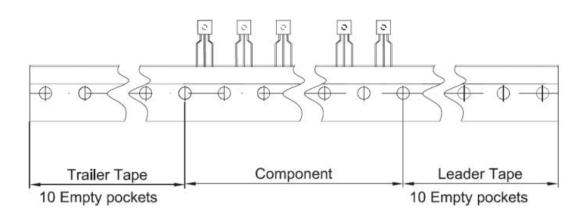
Cloudchild reserve the right to make modifications, enhancements, improvements, crrections or other changes without further notice to any product herein. Cloudchild does not assume any liability arising out of the application or use of any product described herein.

ChongQing Cloudchild Technology Co., Ltd. (short for Cloudchild) exerts the greatest possible effort to ensure high quality and reliability. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing Cloudchild products, to comply with the standards of safety in making a safe design for the entire system, including redundancy, fire-prevention measures, and malfunction prevention, to prevent any accidents, fires, or community damage that may ensue. In developing your designs, please ensure that Cloudchild products are used within specified operating ranges as set forth in the most recent Cloudchild products specifications.

TO-29 Tape and Reel



		D	imiensio	ons are i	n millime	ter		
A1	Α	Т	Р	P0	P2	F1	F2	W
4.5	4.5	3.5	12.7	12.7	6.35	2.5	2.5	18.0
W0	W1	W2	Н	НО	D0	t1	t2	ΔΡ
6.0	9.0	1.0 MAX.	19.0	16.0	4.0	0.4	0.2	0



Package	Box	Box Size(mm)	Carton	Carton Size(mm)	
TO-92	2000 pcs	333×162×43	20,000 pcs	350×340×250	

Date of change	Rev#	revise content
2023/06/06	A/0	/